

MICROWAVE LOW NOISE AMPLIFIER  
NPN SILICON EPITAXIAL TRANSISTOR  
(WITH BUILT-IN 2 ELEMENTS) MINI MOLD

## FEATURES

- Low Noise, High Gain
- Operable at Low Voltage
- Small Feed-back Capacitance  
 $C_{re} = 0.4 \text{ pF TYP.}$
- Built-in 2 Transistors ( $2 \times 2\text{SC4959}$ )

## ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKING STYLE
$\mu$ PA806T	Loose products (50 PCS)	Embossed tape 8 mm wide. Pin 6 (Q1 Base), Pin 5 (Q2 Base), Pin 4 (Q2 Emitter) face to perforation side of the tape.
$\mu$ PA806T-T1	Taping products (3 KPCS/Reel)	

**Remark** If you require an evaluation sample, please contact an NEC Sales Representative. (Unit sample quantity is 50 pcs.)

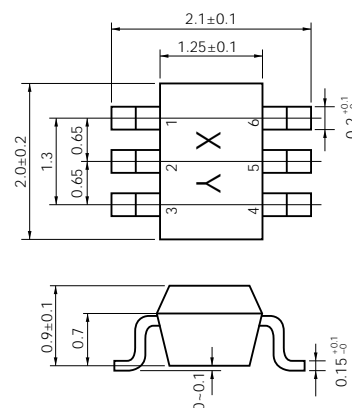
ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

PARAMETER	SYMBOL	RATING	UNIT
Collector to Base Voltage	$V_{CBO}$	9	V
Collector to Emitter Voltage	$V_{CEO}$	6	V
Emitter to Base Voltage	$V_{EBO}$	2	V
Collector Current	$I_C$	30	mA
Total Power Dissipation	$P_T$	150 in 1 element 200 in 2 elements <sup>Note</sup>	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-65 to +150	$^\circ\text{C}$

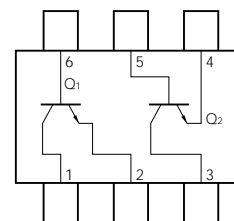
**Note** 110 mW must not be exceeded in 1 element.

## PACKAGE DRAWINGS

(Unit: mm)



## PIN CONFIGURATION (Top View)



## PIN CONNECTIONS

1. Collector (Q1)
2. Emitter (Q1)
3. Collector (Q2)
4. Emitter (Q2)
5. Base (Q2)
6. Base (Q1)

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)**

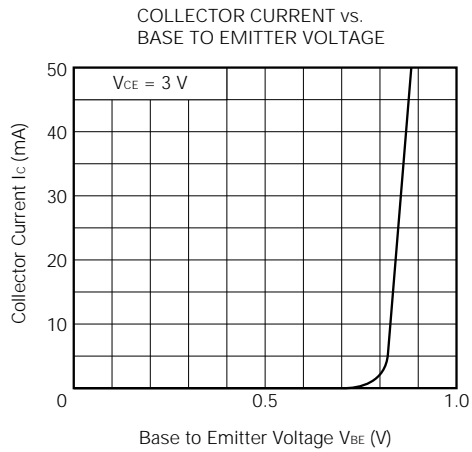
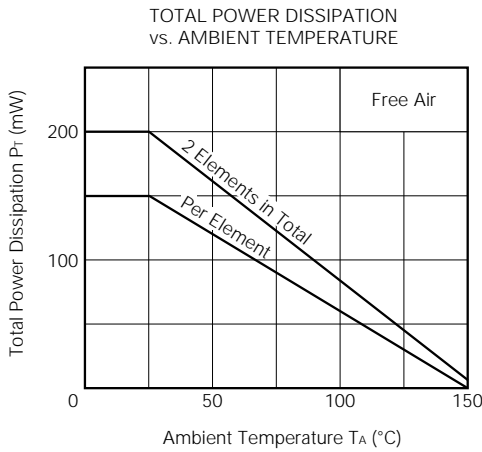
PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cutoff Current	I <sub>CB0</sub>	V <sub>CB</sub> = 5 V, I <sub>E</sub> = 0			0.1	μA
Emitter Cutoff Current	I <sub>EB0</sub>	V <sub>EB</sub> = 1 V, I <sub>C</sub> = 0			0.1	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 10 mA <sup>Note 1</sup>	75		150	
Gain Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 10 mA, f = 2 GHz		12		GHz
Feed-back Capacitance	C <sub>re</sub>	V <sub>CB</sub> = 3 V, I <sub>E</sub> = 0, f = 1 MHz <sup>Note 2</sup>		0.4	0.7	pF
Insertion Power Gain	S <sub>21</sub>   <sup>2</sup>	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 10 mA, f = 2 GHz	7	8.5		dB
Noise Figure	NF	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 3 mA, f = 2 GHz		1.5	2.5	dB
h <sub>FE</sub> Ratio	h <sub>FE1</sub> /h <sub>FE2</sub>	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 10 mA A smaller value among h <sub>FE</sub> of h <sub>FE1</sub> = Q1, Q2 A larger value among h <sub>FE</sub> of h <sub>FE2</sub> = Q1, Q2	0.85			

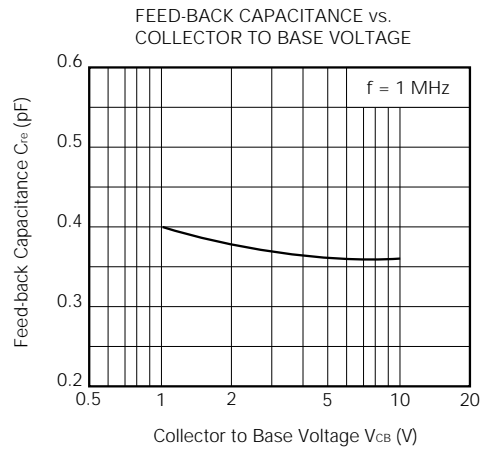
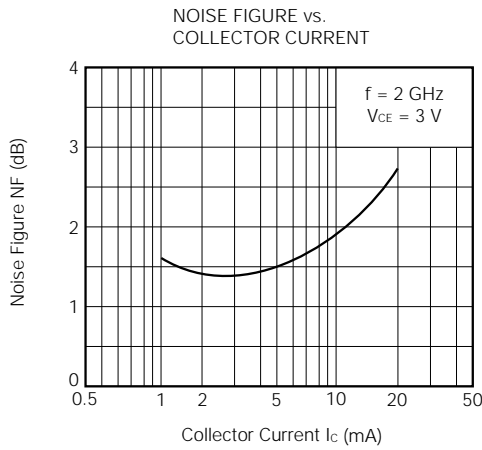
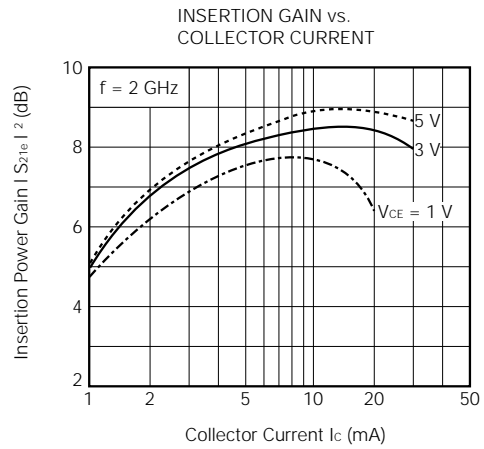
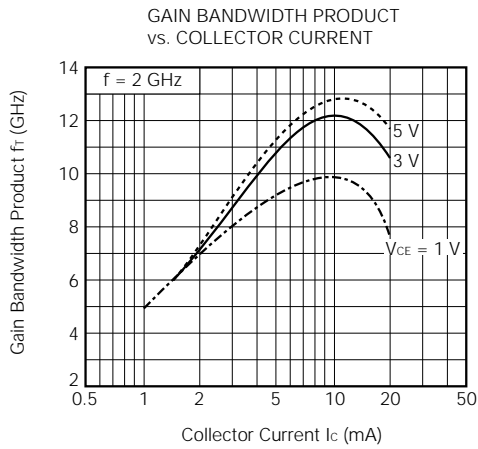
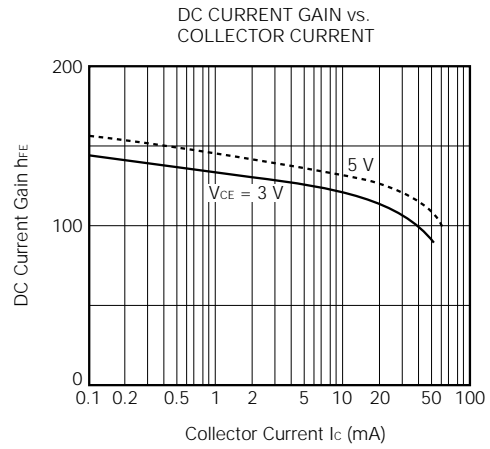
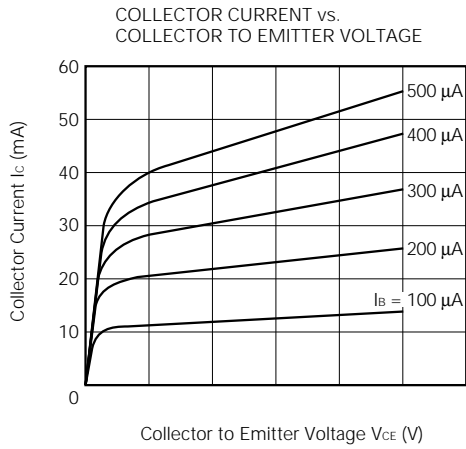
- Notes**
1. Pulse Measurement: P<sub>w</sub> ≤ 350 μs, Duty cycle ≤ 2 %
  2. Measured with 3-pin bridge, emitter and case should be connected to guard pin of bridge.

**h<sub>FE</sub> CLASSIFICATION**

Rank	KB
Marking	T83
h <sub>FE</sub> Value	75 to 150

**TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)**





S-PARAMETERS

$V_{CE} = 3\text{ V}$ ,  $I_c = 1\text{ mA}$ ,  $Z_O = 50\ \Omega$

f GHz	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.200	0.9340	-15.7	3.5100	164.8	0.0450	82.6	0.9850	-8.7
0.400	0.9040	-29.4	3.3520	150.7	0.0780	68.0	0.9410	-17.1
0.600	0.8150	-43.4	3.1060	138.0	0.1140	62.8	0.8960	-23.6
0.800	0.7530	-56.6	2.8840	126.3	0.1370	58.0	0.8260	-29.9
1.000	0.6540	-68.9	2.6050	115.1	0.1490	55.2	0.7830	-34.7
1.200	0.5900	-79.8	2.4490	105.4	0.1660	45.4	0.7220	-38.0
1.400	0.5160	-90.1	2.2610	96.8	0.1770	44.8	0.6790	-42.0
1.600	0.4590	-101.5	2.0780	89.4	0.1780	45.1	0.6430	-45.2
1.800	0.4230	-110.8	1.9250	83.7	0.1880	42.5	0.6290	-46.8
2.000	0.3670	-123.9	1.8700	76.3	0.1900	41.9	0.5880	-51.4
2.200	0.3370	-136.7	1.7790	69.9	0.2110	43.9	0.5630	-54.3
2.400	0.3150	-145.5	1.6600	64.1	0.2140	41.9	0.5520	-57.0
2.600	0.3080	-159.1	1.5690	59.4	0.2070	42.8	0.5450	-59.2
2.800	0.2930	-164.8	1.5190	55.3	0.2140	45.8	0.5220	-64.5
3.000	0.2950	-179.6	1.4610	50.7	0.2260	45.4	0.4960	-61.3

$V_{CE} = 3\text{ V}$ ,  $I_c = 3\text{ mA}$ ,  $Z_O = 50\ \Omega$

f GHz	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.200	0.8020	-25.9	8.8990	154.2	0.0370	67.2	0.9420	-15.7
0.400	0.6780	-45.8	7.4880	134.4	0.0760	65.6	0.8040	-26.6
0.600	0.5440	-62.8	6.1260	119.6	0.0860	60.9	0.7060	-33.2
0.800	0.4430	-75.7	5.1230	108.1	0.1050	58.4	0.6250	-36.6
1.000	0.3540	-87.3	4.3050	99.1	0.1210	55.9	0.5660	-38.3
1.200	0.2930	-99.7	3.7880	91.3	0.1330	61.2	0.5190	-41.4
1.400	0.2360	-108.4	3.3560	84.8	0.1440	55.4	0.4950	-43.9
1.600	0.2000	-121.0	3.0100	79.1	0.1570	56.2	0.4660	-44.5
1.800	0.1820	-129.5	2.6960	74.4	0.1760	58.0	0.4560	-44.5
2.000	0.1480	-151.7	2.5340	69.4	0.1940	56.1	0.4310	-48.8
2.200	0.1370	-166.1	2.3820	64.0	0.2150	56.3	0.4050	-51.9
2.400	0.1340	175.2	2.1870	60.0	0.2130	57.8	0.3990	-52.8
2.600	0.1640	169.7	2.0530	55.8	0.2410	57.6	0.3950	-52.9
2.800	0.1500	170.9	1.9660	53.0	0.2490	55.2	0.3750	-59.2
3.000	0.1780	147.7	1.8710	49.6	0.2750	56.6	0.3740	-60.8

S-PARAMETERS

V<sub>CE</sub> = 3 V, I<sub>c</sub> = 5 mA, Z<sub>O</sub> = 50 Ω

f GHz	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.200	0.6900	-33.3	12.2960	147.1	0.0320	74.8	0.8850	-19.7
0.400	0.5360	-54.7	9.4300	125.5	0.0610	66.3	0.7210	-30.3
0.600	0.4010	-70.0	7.2390	111.3	0.0700	59.6	0.6030	-34.5
0.800	0.3150	-82.4	5.8220	101.1	0.0950	63.8	0.5230	-36.7
1.000	0.2360	-93.8	4.7830	93.4	0.1090	62.3	0.4870	-38.0
1.200	0.1850	-105.4	4.1700	86.4	0.1260	61.9	0.4600	-38.8
1.400	0.1440	-115.8	3.6410	80.7	0.1350	65.9	0.4360	-40.4
1.600	0.1230	-134.4	3.2380	76.1	0.1560	61.2	0.4170	-42.6
1.800	0.1040	-144.6	2.8910	71.4	0.1770	62.4	0.4020	-43.9
2.000	0.1000	-170.6	2.7040	67.3	0.1930	60.7	0.3940	-45.8
2.200	0.1110	167.4	2.5330	62.6	0.2080	60.6	0.3710	-50.3
2.400	0.1040	158.2	2.3270	58.7	0.2260	61.6	0.3500	-50.2
2.600	0.1180	156.3	2.1850	54.9	0.2560	58.2	0.3560	-51.2
2.800	0.1190	150.0	2.0910	52.6	0.2560	56.8	0.3520	-58.1
3.000	0.1490	142.4	1.9760	49.0	0.2860	56.6	0.3410	-56.9

V<sub>CE</sub> = 3 V, I<sub>c</sub> = 10 mA, Z<sub>O</sub> = 50 Ω

f GHz	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.200	0.5080	-43.6	17.0900	135.9	0.0330	63.8	0.7930	-26.2
0.400	0.3410	-65.3	11.3980	114.2	0.0520	68.5	0.5910	-32.9
0.600	0.2320	-80.7	8.2250	102.0	0.0690	69.0	0.5130	-32.9
0.800	0.1770	-90.8	6.3950	93.8	0.0880	71.6	0.4480	-32.8
1.000	0.1220	-108.2	5.1870	87.2	0.1060	69.3	0.4180	-35.9
1.200	0.1010	-121.8	4.4390	81.6	0.1260	70.1	0.4030	-33.3
1.400	0.0670	-138.2	3.8770	76.9	0.1450	70.5	0.3930	-36.5
1.600	0.0620	-167.6	3.4350	72.4	0.1590	65.5	0.3680	-36.2
1.800	0.0660	-171.3	3.0650	68.8	0.1790	65.0	0.3610	-39.5
2.000	0.0770	146.7	2.8540	65.0	0.2060	63.9	0.3480	-42.3
2.200	0.0990	146.5	2.6590	60.5	0.2220	62.8	0.3360	-46.6
2.400	0.1140	128.1	2.4400	57.0	0.2420	60.9	0.3370	-48.8
2.600	0.1260	136.8	2.2790	53.5	0.2660	59.9	0.3170	-47.2
2.800	0.1020	129.6	2.1950	50.9	0.2770	59.6	0.3280	-55.1
3.000	0.1370	123.5	2.0800	47.9	0.2860	58.3	0.3100	-51.2

## [MEMO]

No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customer must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.

NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices in "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.